

L Number	Hits	Search Text	DB	Time stamp
1	7963	support adj substrate	USPAT; US-PGPUB	2003/07/25 14:15
2	1	(support adj substrate) same (bias adj electrode)	USPAT; US-PGPUB	2003/07/25 14:18
3	1	(support adj substrate) with (bias adj electrode)	USPAT; US-PGPUB	2003/07/25 14:32
4	770	gas adj barrier adj layer	USPAT; US-PGPUB	2003/07/25 14:32
5	770	gas adj barrier adj layer	USPAT; US-PGPUB	2003/07/25 14:33
-	1	"20020092992" .pn.	USPAT; US-PGPUB	2003/07/25 08:07
-	1	20020092992.pn.	USPAT; US-PGPUB	2003/06/19 13:52
-	78	250/370.12.cccls.	USPAT; US-PGPUB	2003/06/19 13:53
-	139	250/370.13.cccls.	USPAT; US-PGPUB	2003/06/19 13:53
-	382	250/338.4.cccls.	USPAT; US-PGPUB	2003/06/19 13:53
-	1179	250/338.1.cccls.	USPAT; US-PGPUB	2003/06/19 13:53
-	516	250/336.1.cccls.	USPAT; US-PGPUB	2003/06/19 13:53
-	486	250/370.01.cccls.	USPAT; US-PGPUB	2003/06/19 13:53
-	2432	250/370.12.cccls. or 250/370.13.cccls. or 250/338.4.cccls. or 250/338.1.cccls. or 250/336.1.cccls. or 250/370.01.cccls.	USPAT; US-PGPUB	2003/06/19 13:54
-	29	((250/370.12.cccls. or 250/370.13.cccls. or 250/338.4.cccls. or 250/338.1.cccls. or 250/336.1.cccls. or 250/370.01.cccls.) and (active adj matrix))	USPAT; US-PGPUB	2003/07/24 09:00
-	83	resin and film and (active adj matrix) and (charge adj transfer) and substrate	USPAT; US-PGPUB	2003/07/24 07:52
-	52	(resin and film and (active adj matrix) and (charge adj transfer) and substrate) and semiconduct\$4	USPAT; US-PGPUB	2003/07/24 08:41
-	591	Metal adj bump	USPAT; US-PGPUB	2003/07/24 08:18
-	1	"20010032942" .pn.	USPAT; US-PGPUB	2003/07/24 08:26
-	1	20020074503.pn.	USPAT; US-PGPUB	2003/07/24 08:33
-	23	spartiotis.in.	USPAT; US-PGPUB	2003/07/24 08:33
-	1	5880472.URPN.	USPAT	2003/07/24 08:45
-	17	("3041166" "3975635" "4286033" "4338387" "4463279" "4554453" "4770965" "4891290" "4990419" "5021310" "5023661" "5198673" "5235195" "5320927" "5330863" "5396072" "5436101").PN.	USPAT	2003/07/24 08:45
-	3877	Direct adj conversion	USPAT; US-PGPUB	2003/07/24 09:00
-	729	(Direct adj conversion) and semiconduct\$4	USPAT; US-PGPUB	2003/07/24 09:00
-	24	((Direct adj conversion) and semiconduct\$4) and (active adj matrix)	USPAT; US-PGPUB	2003/07/24 09:33
-	1	5,652,430.pn.	USPAT; US-PGPUB	2003/07/24 09:06
-	62	((Direct adj conversion) and semiconduct\$4) and resin	USPAT; US-PGPUB	2003/07/24 10:02
-	1	(resin and film and (active adj matrix) and (charge adj transfer) and substrate) and semicond\$4	USPAT; US-PGPUB	2003/07/24 17:02
-	1	6407374.pn.	USPAT; US-PGPUB	2003/07/24 09:33

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C:\APPS\EAST\Workspaces\09987920.wsp

-	615647	curved detector	USPAT;	2003/07/24
-	3201	curved same detector	US-PGPUB	10:02
-	74	curved adj detector	USPAT;	2003/07/24
-	752	(active adj matrix) same resin	US-PGPUB	10:03
-	0	6171643.pn	USPAT;	2003/07/24
-	1	6171643.pn.	US-PGPUB	10:26
-	14479	Thermal adj expansion adj coefficient	USPAT;	2003/07/24
-	1166	(Thermal adj expansion adj coefficient) with resin	US-PGPUB	10:35
-	337	((Thermal adj expansion adj coefficient) with resin) same substrate	USPAT;	2003/07/24
-	2	((Thermal adj expansion adj coefficient) with resin) same substrate) and (direct adj conversion)	US-PGPUB	17:03
-	4665	resin adj substrate	USPAT;	2003/07/24
-	1606	(resin adj substrate) and semiconduct\$3	US-PGPUB	17:03
-	2	((resin adj substrate) and semiconduct\$3) and (direct adj conversion)	USPAT;	2003/07/25
-	1443	((resin adj substrate) and semiconduct\$3) and layer	US-PGPUB	08:10
-	241	((resin adj substrate) and semiconduct\$3) and conversion	USPAT;	2003/07/25
-	273	((resin adj substrate) and semiconduct\$3) and (detector or sensor or photodetector or photosensor)	US-PGPUB	08:08
-	55	(resin adj substrate) near flexible	USPAT;	2003/07/25
-	35	flexible adj detector	US-PGPUB	08:11
-	1	5880472.pn.	USPAT;	2003/07/25
-	1	6512233.pn.	US-PGPUB	09:15
-	905561	gas adj barrier layer	USPAT;	2003/07/25
			US-PGPUB	09:45
			USPAT;	14:14
			US-PGPUB	10:20